



EXPEDITED PROCEDURE - EXAMINING GROUP 2826

S/N 09/941123

Please do NOT enter. Thanks: *[Signature]* PATENT (3/5/3) J. Mondt

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Gurtej S. Sandhu et al.

Examiner: Johannes P Mondt

Serial No.: 09/941123

Group Art Unit: 2826

Filed: August 28, 2001

Docket No.: 303.676US3

Title: CHEMICAL VAPOR DEPOSITION OF TITANIUM

#8/Amend  
C/E  
Amend  
3/4/03

AMENDMENT & RESPONSE UNDER 37 C.F.R. § 1.116

Box AF  
Commissioner for Patents  
Washington, D.C. 20231

RECEIVED  
FEB 26 2003  
TECHNOLOGY CENTER 2800

In response to the final Office Action mailed December 18, 2002, please amend the application as follows:

IN THE CLAIMS

Please substitute the claim set in the appendix entitled Clean Version of Pending Claims for the previously pending claim set. The substitute claim set is intended to reflect amendment of previously pending claim 59. The specific amendments to individual claims are detailed in the following marked up set of claims.

cl 59. (Amended) A memory device, comprising:

a memory array;

a control circuit operatively coupled to the memory array; and

an I/O circuit operatively coupled to the memory array;

wherein at least one of the memory array, control circuit and I/O circuit comprises a titanium alloy layer formed on overlying walls of a contact opening, wherein the titanium alloy layer is produced using a method, the method comprising:

forming a seed layer [supported by a substrate] within the contact opening by combining a first precursor with a first reducing agent; and

forming the titanium alloy layer [supported by a substrate] within the contact opening by combining a titanium-containing precursor with the seed layer.